Competing pairing interactions responsible for the large upper critical field in a stoichiometric iron-based superconductor, CaKFe₄As₄

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(Dated: June 15, 2021)

The upper critical field of multi-band superconductors is an important quantity that can reveal the details about the nature of the superconducting pairing. Here we experimentally map out the complete upper critical field phase diagram of a stoichiometric superconductor, CaKFe₄As₄, up to 90 T for different orientations of the magnetic field and at temperatures down to 4.2 K. The upper critical fields are extremely large, reaching values close to ~ 3Tc at the lowest temperature, and the anisotropy decreases dramatically with temperature leading to essentially isotropic superconductivity at 4.2 K. We find that the temperature dependence of the upper critical field can be well described by a two-band model in the clean limit with band coupling parameters favouring intraband over interband interactions. The large Pauli paramagnetic effects together with the presence of the shallow bands is consistent with the stabilization of an FFLO state at low temperatures in this clean superconductor.

CaKFe₄As₄ is a clean and stoichiometric superconductor with a relatively high Tc = 35 K and it belongs to a new family of 1144 iron-based superconductors [5]. This system lacks long-ranged magnetic order or a nematic electronic state at low temperatures [5–11] but upon doping with Ni a hedgehog magnetic structure is stabilized [9, 12, 13]. CaKFe₄As₄ has an exceptionally large critical current density due to the strong point-like defects caused by local structural site effects as well as surface pinning [14–16]. Due to reduced symmetry compared with the 122 family of iron-based superconductors, CaKFe₄As₄ is predicted to have up to ten different bands (Fig. 1(e) and Fig. 4 in the Appendix). However, angle resolved photoemission spectroscopy detects a Fermi surface composed of three hole pockets and two electron pockets. The superconducting gaps are nearly isotropic and different for each of the Fermi surface sheets [4]. The presence of electron and hole sheets supports a spin resonance corresponding to the (π, π) nesting wave vector detected by neutron diffraction [6] and promotes a s± superconducting pairing symmetry in CaKFe₄As₄. Thus, this clean system is a model system for understanding the effect of pairing on its upper critical field.

In order to understand the superconducting properties of CaKFe₄As₄ we have measured the upper critical fields for two orientations in magnetic fields up to 90 T using electrical transport measurements. These experimental studies provide a complete Hc2(T) phase diagram and allow us to model the entire temperature dependence, as previous work in magnetic fields up to 60 T could not reach the low temperature region [7]. We find that CaKFe₄As₄ is highly isotropic at the lowest temperature. A two-band model describes the dependence of the upper critical fields for both directions and the band coupling parameters indicate the presence of different pairing channels. At low temperatures, the upper critical field does not saturate but shows an upturn, consistent with the emergence of a FFLO state in CaKFe₄As₄.

Experimental details. Single crystals of CaKFe₄As₄ were grown in the Ames Laboratory, as discussed elsewhere [5, 17]. Robust electrical contacts were achieved using indium solder, giving contact resistances of less than 0.5 Ω. Samples were measured using the standard 4- and 5-point ac lock-in techniques and a current of 1 mA. We have investigated several high quality single crystals, with large residual resistivity ratios ~ 14.5 (RRR = ρ(300 K)/ρ(30 K)), small residual resistivity, ρ₀ ~ 9.4 μΩ cm, and sharp superconducting transitions, ΔTc ~ 0.1 K (see Figs. 1(f) and 5(c) in the Appendix). Transport measurements were performed in Oxford up to 16 T in a Quantum Design PPMS in constant magnetic fields and for different magnetic field orientations (H||c and H||ab). Pulsed magnetic field measurements were performed at LNCMI Toulouse, using a 70 T single coil and a 90 T dual coil at constant temperatures below 35 K for both field orientations. Magnetic fields up to 90 T were produced by using current pulses through two different solenoid coils (an example is shown in Fig. 6 in the Appendix).
Upper critical field from transport measurements. Fig. 1 shows resistivity against temperature for different fixed magnetic fields for orientations of the sample in relation to the applied magnetic field. As the magnetic field increases the superconducting transition becomes broader and suppressed faster for $H||c$ by 5 K in 16 T (Fig. 1(a)), as compared with the $H||(ab)$ case for which $H_{c2}$ only changes by 2 K in 16 T (Fig. 1(b)), as the orbital effects are less effective in suppressing superconductivity in this orientation. These data are used to extract the upper critical field near $T_c$, defined as the offset field, as shown in Fig. 5(a) and (b) in the Appendix. Due to the high crystallinity of our samples that display sharp superconducting transitions, we find that the critical temperature from magnetization measurements is similar to the offset temperature determined from transport measurements (Fig. 5(a)). In order to completely suppress the superconductivity of CaKFe$_4$As$_4$ we have used pulsed magnetic fields up to 90 T. Resistivity data against magnetic fields up to 90 T measured at fixed temperature are shown in Fig. 1(c) and 1(d) for the two different orientations. Despite the strong disparity in the degree of suppression of superconductivity between the two field directions close to $T_c$, at the lowest measurable temperature of 4.2 K the normal state is reached at a similar field $\sim 85$ T for both orientations.

Upper critical field phase diagram. Based on these experimental data, we have constructed the complete upper critical field phase diagram of CaKFe$_4$As$_4$ down to 4.2 K as shown in Fig. 2(a) for the two orientations. Our results are in good agreement with previous studies up to 60 T for both offset and onset critical fields [7] (see Fig. 9(a) and (b)) and reveal extremely large upper critical fields, reaching almost $\sim 3T_c$ at the lowest temperatures. These values are above the Pauli paramagnetic limit, $\sim 1.85T_c$, estimated to be $\sim 65$ T for a single-band superconductor and assuming $g=2$ and the weak coupling limit. The anisotropy of the upper critical field, defined as the ratio of the upper critical field for different orientations, $\Gamma = H_{c2}^{||c}/H_{c2}^{||ab}$, drops dramatically with decreasing temperature from $\sim 4$ to 1, as shown in Fig. 2(b). Interestingly, the upper critical fields for the two orientations cross at $T \sim 4.2$ K, leading to isotropic superconducting behaviour in the low temperature limit. This phenomenon has been found in optimally doped iron-based superconductors, such as FeSe$_{0.5}$Te$_{0.5}$ [18, 19] and (Ba,K)Fe$_2$As$_2$ [20]. This behaviour reflects the large Pauli paramagnetic effects in iron-based superconductors and the influence of Fermi surface details on limiting the orbital effects [20]. The Fermi surface of CaKFe$_4$As$_4$ has significant warping for the outer electron and hole band that can potentially allow circulating currents out of plane (see Fig. 4(d) in the Appendix). Furthermore, the calculated anisotropy of the penetration depth based on plasma frequencies (as in Ref.21) is $\Gamma = \lambda_c/\lambda_{ab} \sim 4.5$, (see Fig. 4 in the Appendix) similar to the measured anisotropy close to $T_c$ (Fig. 2(b)), suggesting that the Fermi surface details play an important role in understanding its superconducting proper-
Having experimentally determined the upper critical fields for different orientations in magnetic field, we can extract the associated coherence lengths in different temperature regimes, as detailed in the Appendix. In the vicinity of $T_c$, the Ginzburg-Landau coherence lengths shown in Fig. 2(b) are $\xi_{ab} = 1.66(4) \text{ nm}$ and $\xi_c = 0.53(2) \text{ nm}$ for CaKFe$_4$As$_4$, similar to previously reported values [7]. In the low temperature limit, we find coherence lengths of $\xi_{ab} = 1.83(3) \text{ nm}$ and $\xi_c = 1.87(6) \text{ nm}$, as shown in Fig. 7 in the Appendix. This demonstrates the presence of an isotropic superconducting state at lowest temperature in CaKFe$_4$As$_4$. The coherence lengths approach the 3D to 2D crossover close to $c/\sqrt{2} \sim 0.911 \text{ nm}$, as shown in Fig. 2(b) [5, 22]). The low temperature extracted $\xi$ values are larger than $~0.7 \text{ nm}$ reported from STM measurements, which probe locally the vortex lattice rather than an overall averaged effect [23]. Knowing the coherence length, allows us to estimate the depairing current density, $J_{\text{ab}}$, as described in the Appendix [24]. Previous magnetisation data reported a value of $\mu_0 H_{c1} = 22(1) \text{ mT}$ when $H||c$ at low temperature which, combined with $H_{c2}$ reported here, give $\kappa 99(2)$ and $\lambda = 183(6)$ nm. Using this value for the penetration depth and $\xi = 1.86(3) \text{ nm}$ gives $J_{\text{ab}} = 1.61(9) \times 10^6 \text{ A/cm}^2$, which is one of the largest among iron-based superconductors. This supports the extremely large critical current densities, reported previously for CaKFe$_4$As$_4$ in Ref. [14]. The small coherence length of CaKFe$_4$As$_4$ is compatible with the presence of the large upper critical field, consistent with small Fermi velocities and high $T_c$ values of CaKFe$_4$As$_4$ ($\xi \sim \hbar v_F/(2\pi k_B T_c)$ [1]). Surface superconductivity can survive in a thin layer of thickness $\sim \xi$ in systems with clean surfaces and it can lead to a critical field larger than $H_{c2}$. In order to establish the importance of those effects, future angular-dependent studies would be necessary to identify the role played by surface superconductivity in CaKFe$_4$As$_4$ close to $T_c$. Using the extrapolated zero-temperature normal state resistivity $\rho_0 \sim 4.9 \Omega \text{cm}$ in Fig. 1(f) and carrier concentrations from Ref. 7, we can estimate a mean free path of $\ell = 26.6 \text{ nm}$. Since the mean free path due to elastic scattering from impurities is far larger than the coherence length, $(\xi 0) < \ell$, CaKFe$_4$As$_4$ can be described as being in the clean limit. Resistivity data in Fig. 1(f) show also a sharp superconducting transition indicating a high quality single crystal. Furthermore, the extrapolated high-field resistivity at low temperatures (see Fig. 4(d) in the Appendix) displays a $T^2$ dependence indicative of a Fermi-liquid behaviour that extends up to $\sim 55 \text{ K}$.

In order to assess the role of orbital and Pauli paramagnetic effects on the upper critical field of CaKFe$_4$As$_4$ we first describe the temperature dependence of the upper critical field using the three-dimensional Werthamer-Helfand-Hohenberg (WHH) model [25], with the inclusion of spin paramagnetism effects. The slope close to $T_c$ ($H_{c2} = -dH_{c2}/dT|_{T=T_c}$) is used to estimate the zero-temperature orbital upper critical field and $H_{c2}^{\text{orb}} = 0.73 H_{c2}^\text{WHH}$ for the clean limit ($0.69 H_{c2}^\text{WHH}$ in the dirty limit) for a single-band weak-coupling superconductor with ellipsoidal Fermi surface [26]. We find that the orbital pair breaking dominates the temperature dependence for $H||c$ down to 10 K, below which it deviates, as shown in Fig. 2(c). However, when the magnetic field is aligned along the conducting $(ab)$ plane, a Pauli pair breaking contribution has to be included which reduces the orbital-limited critical field by $\mu_0 H_F = \mu_0 H_{c2}^\text{orb}/\sqrt{1 + \alpha^2}$, where $\alpha$ is the Maki pa-
rameter. The extracted Maki parameter $\alpha$ is small where the orbital effects dominate ($\alpha \sim 0.25$ for $H || c$), but it becomes significant reaching $\alpha = 4.2$ for $H || (ab)$ (see Fig. 2(c)). This value is close to that of FeSe$_{0.6}$Te$_{0.6}$ single crystals where $\alpha \sim 5.5$ suggesting that the upper critical field is dominated by Pauli paramagnetic effects [27]. Strong paramagnetic effects are an important signature of optimally doped iron-based superconductors [28–32]. For a clean isotropic single-band, the Maki parameter is given by $\alpha = \pi^2 \Delta (4E_F)$. The values of the measured superconducting gap $\Delta$ varies between 2.4 – 13 meV whereas the Fermi energies vary significantly for different bands, being smallest for the inner hole band, $\alpha$ ($\sim 3$ meV) and the shallow electron band $\delta$ ($\sim 10$ meV) [4, 33]. The band structure calculation predicts four electron pockets centred at the $M$ point, as shown in Fig. 4 in the Appendix. Experimentally, only one electron pocket can be resolved in experiments due to a significant intrinsic linewidth and the fact that the bottom of these bands is located very close to Fermi level [4]. Thus, the presence of the shallow bands, together with the small Fermi energies $E_F$ and large superconducting gap $\Delta$ create conditions for large $\alpha$ and Pauli pair-breaking.

**Upper critical field described by a two-band model.**

In order to describe the complete temperature dependence of $H_{c2}(T)$ for CaKFe$_4$As$_4$, including the upturn below $\sim 10$ K for both orientations, a two-band model in the clean limit is considered, as detailed in Ref. 1 and in the Appendix. This model accounts for the presence of two different bands, with interband scattering ($\lambda_{11}, \lambda_{22}$) and intraband effects ($\lambda_{12}, \lambda_{21}$) and includes paramagnetic effects and allows for the presence of an FFLO inhomogeneous state at high-fields and low temperatures [1]. An FFLO state is characterized by a real-space modulation of the superconducting order parameter either in amplitude or phase such that the system energy is minimized under the constraints of a large Zeeman energy and superconducting condensation energy [2]. As the FFLO wave vector $Q$ appears spontaneously below a certain temperature, $T_{\text{FFLO}}$, the spinodal instability line in $H_{c2}(T)$ at a finite $Q$ acquires the characteristic upturn [1].

In most iron-based superconductors, the pairing is expected to be mediated by spin-fluctuations leading to a sign changing $s_{\pm}$ order parameter. In this case, upper critical fields are generally described by dominant interband coupling parameters with $\lambda_{11} = \lambda_{22} = 0$ and $\lambda_{12} = \lambda_{21} \sim 0.5$ ($\lambda_{11,22} \ll \lambda_{12,21}$) [3, 7, 28, 29, 34, 35]. Furthermore, in these multiband systems orbital fluctuations can dominate the pairing interactions in certain conditions favouring a gap with equal sign on each pocket, resulting in the $s^{++}$ pairing [36] ($\lambda_{11,22} \gg \lambda_{12,21}$).

To model the upper critical fields for both field orientations, we have considered different input parameters from previous experiments on CaKFe$_4$As$_4$. For example, the ratio between the extreme velocities of the Fermi surfaces is taken from ARPES experiments [33] and it gives a starting value of $\eta_c \sim 0.02$, which is the squared velocity ratio between the two bands. Upper critical field simulations have a strong sensitivity to $\eta$ values, as shown in Fig. 8 in the Appendix and it can change for different field orientations due to differences in the in-plane velocities on the Fermi surface (see Figs. 1(e) and 4 in the Appendix). We assume that $s=1$ (defined by Eq. 9 in the Appendix) for both field orientations and the starting values of the Maki parameters are those from the single band model of

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**FIG. 3.** Upper critical fields for (a) $H || c$ (solid squares) and (b) and (c) $H || (ab)$ (open triangles) described by the two-band model. The dotted lines correspond to $s^{+}$ pairing ($\lambda_{11} = \lambda_{22} = 0$, $\lambda_{12} = \lambda_{21} \sim 0.5$, $\alpha_1 = 0.95$, $\alpha_2 = 0$ for $H || c$ and $\alpha_1 = 3.1$ and $\alpha_2 = 0.7$ for $H || (ab)$). Solid lines represent $s^{++}$ pairing ($\lambda_{11} = 0.81$, $\lambda_{22} = 0.29$ and $\lambda_{12} = \lambda_{21} = 0.1$, $\alpha_1 = 0.5$ for $H || c$ and $\alpha_1 = 3.2$, $\alpha_2 = 0$ for $H || (ab)$). The values of $\eta$ vary between $\sim 0.02$ in (a) and $\sim 0.04$ in (b). (c) The temperature dependence of the upper critical field including the emergence of the FFLO state for the two different pairing symmetries with the same parameters as in (b). The lower dashed and red line represents the scaled FFLO $Q/Q(0)$ modulation for $H || (ab)$ for the respective pairing (right axis).
\( H_{c2}(T) \) in Fig. 2(c).

Firstly, the \( H_{c2}(T) \) data are simulated for CaKFe\textsubscript{4}As\textsubscript{4} using parameters corresponding to the \( s^\pm \) case (dashed lines Figs. 3(a) and 3(b)), which provide a reasonable representation of the observed behaviour for both orientations. However, we find that \( H_{c2}(T) \) is best described using \( \lambda_{11} = 0.81 \), \( \lambda_{22} = 0.29 \) and \( \lambda_{12} = \lambda_{21} = 0.1 \) (solid lines in Figs. 3(a) and 3(b)), which is consistent with \( s^{++} \) pairing. For the later model, the constrained Fermi velocities are \( v_1 \sim 380(20) \text{ meVÅ} \) and \( v_2 \sim 54(4) \text{ meVÅ} \) when \( H||c \), and \( v_1 \sim 195(20) \text{ meVÅ} \) and \( v_2 \sim 41(4) \text{ meVÅ} \) when \( H||(a\ b) \) (see Table I). The values of \( v_2 \) are similar in both orientations, indicative of a strongly warped sheet (see Fig. 4 in the Appendix). On the other hand, \( v_1 \) is larger for \( H||c \) and is close to \( \sim 360 \text{ meVÅ} \), reported for the \( a \) hole band from ARPES measurements [33]. The band coupling constants, \( \lambda_{ij} \) that describe our data suggest that the interband scattering due to spin-fluctuations is dominated by the intraband effects in CaKFe\textsubscript{4}As\textsubscript{4}, which can occur in the presence of strong orbital fluctuations [36]. For \( s^{++} \) pairing to overcome \( s^\pm \) pairing it normally requires the presence of strong disorder which leads to similar superconducting gaps on different Fermi surfaces [37]. Furthermore, the band coupling constants for the \( s^{++} \) case resemble those used to describe a two-band superconductor in the dirty limit [38]. However, CaKFe\textsubscript{4}As\textsubscript{4} is clean, suggesting that disorder effects are negligible. Thus, based on the band coupling parameters, we conclude that orbital fluctuations may dominate over spin fluctuations.

When the magnetic field lies along the conducting planes, the low temperature upturn of \( H_{c2}(T) \) in Fig. 3(b) cannot be fully captured by only considering the two-band model with large Pauli paramagnetic effects, \( \alpha \sim 3.2 \). The formation of the FFLO state in a system with a cylindrical Fermi surface requires a large Zeeman energy and a critical Maki’s parameter of \( \alpha_c = 4.76 \) [2], compared to \( \alpha_c = 1.8 \) [39] for a three-dimensional Fermi surface. CaKFe\textsubscript{4}As\textsubscript{4} has a complex Fermi surface with two-dimensional cylindrical and highly warped sheets and together with a large value of \( \alpha \) creates the conditions for the emergence of an FFLO state [1]. A FFLO state can be realized in very clean materials with weak scattering of quasiparticles and it generally manifests as change in slope in the upper critical field at low temperatures [1]. We find indeed that in order to describe the upper critical field data of CaKFe\textsubscript{4}As\textsubscript{4} over the entire temperature range, a FFLO state could be stabilized below \( T_{\text{FFLO}} \sim 14 \text{ K} \), as shown in Fig. 3(c). Possible contenders to support such an effect are the shallow electron Fermi surface pocket, \( \delta \), in the zone corner which is very close to the Fermi level (\( \sim 10 \text{ meV} \)) as well as the inner hole band \( \alpha (\sim 3 \text{ meV}) \), as detected by ARPES measurements [4].

The temperature dependence of the upper critical field data in CaKFe\textsubscript{4}As\textsubscript{4} implies that the intraband scattering is likely to dominate the interband scattering, the latter of which being promoted by spin fluctuations. In the presence of spin-orbit coupling the orbital fluctuations can lead to \( s^{++} \) pairing, as suggested for LiFeAs [40]. Usually \( s^{++} \) pairing results in far lower critical fields than \( s^\pm \) pairing [1], so our results for CaKFe\textsubscript{4}As\textsubscript{4} are somehow unusual as \( H_{c2} \) is almost \( 3T_c \) at the lowest temperature. The presence of several scattering channels in a multi-band system like CaKFe\textsubscript{4}As\textsubscript{4} can increase the upper critical field to a much greater extent than in single gap superconductors, caused by the relative weight of different scattering channels. CaKFe\textsubscript{4}As\textsubscript{4} theoretically has up to six large cylindrical hole bands, (with the equivalent of 50% hole doping in a 122 iron-based superconductor) providing a large density of states (see Fig. 1(c), Fig. 4 in the Appendix and Ref. 33) and it can also promote intraband scattering driven by orbital or electron-phonon couplings. On the other hand, the shallow bands in CaKFe\textsubscript{4}As\textsubscript{4} are likely to be involved in the stabilization of the FFLO state. Thus, the temperature dependence of the upper critical field of CaKFe\textsubscript{4}As\textsubscript{4} can reflect the behaviour of two dominant superconducting gaps that reside on different sheets of the cylindrical Fermi surface, possibly one on a large hole band and another one on a shallow small band.

In summary, we have experimentally mapped the upper critical fields of CaKFe\textsubscript{4}As\textsubscript{4} up to 90 T and down to 4.2 K, providing a complete phase diagram for this stoichiometric superconductor. The anisotropy decreases dramatically with temperature, the system becoming essentially isotropic near 4 K. Upper critical fields are extremely large in this system, reaching close to \( \sim 3T_c \) at the lowest temperature, well above the expectation based on conventional single-band superconductivity. Instead, the temperature dependence of the upper critical field can be described using by a two-band model in the clean limit. The band coupling constants suggest a dominant orbital pairing over spin fluctuations pairing in CaKFe\textsubscript{4}As\textsubscript{4}. Furthermore, for magnetic fields aligned in the conducting plane and due to large Pauli paramagnetic effects, we find that the temperature dependence of the upper critical field is consistent with the emergence of an FFLO state at low temperatures.

Acknowledgements We thank Alex Gurevich for helpful discussions related to the two-band modelling of the upper critical field and Jérôme Béard, Marc Nardone, Abdelaziz Zitouni for the technical support during the pulsed field experiments. This work was mainly supported by Oxford Centre for Applied Superconductivity. P.R. acknowledges the support of the Oxford Quantum Materials Platform Grant (EP/M020517/1). Part of this work was supported HFML-RU/FOM and LNCMI-CNRS, members of the European Magnetic Field Laboratory (EMFL) and by EPSRC (UK) via its membership to the EMFL (grant no. EP/N01085X/1). Part of this work at the LNCMI was supported by Programme Investissements d’Avenir under the program ANR-11-IDEX-0002-02, reference ANR-10-LABX-0037-NEXT. Work at Ames Laboratory was supported by the U.S. Department of Energy, Office of Basic Energy Science, Division of Materials Sciences and Engineering. Ames Laboratory is operated for the U.S. Department of Energy by Iowa State University under Contract No. DE-AC02-07CH11358. W.M. was supported by the Gordon and Betty Moore Foundations EPiQS.
Initiative through Grant GBMF4411. We also acknowledge financial support of the John Fell Fund of the Oxford University. AIC acknowledges an EPSRC Career Acceleration Fellowship (EP/1004475/1) and Oxford Centre for Applied Superconductivity.

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APPENDIX

In this section we present additional data to support the findings presented in the main paper.
FIG. 4. Fermi surface of CaKFe$_4$As$_4$. a) Fermi surface with velocity colour. Slices at the b) Γ and b) Z point indicating the size of the different sheets. Solid lines indicate the Brillouin zone. c) Fermi surface slice along the [110] diagonal of the Brillouin zone indicated by the solid lines. The calculations were performed using Wien2k and GGA approximation and the experimental lattice parameters described by the $P4/mmm$ symmetry group were $a=b=3.86590$ Å, $c=12.88400$ Å$[5]$. The calculated value of anisotropy, $\Gamma = \lambda_c / \lambda_{ab} = 313.68 / 70 = 4.5$ using a similar approached used in Ref. $21$. These calculations are in agreement with previous results reported in Ref. $22$. 
FIG. 5. Transport data of CaKFe$_4$As$_4$ as a function of temperature and magnetic field. (a) Estimating the critical temperature, $T_c$, from resistivity against temperature in zero magnetic field (left-axis) and from magnetic susceptibility in a small applied field of 5 mT (right-axis). The midpoint of the transition, $T_{\text{mid}}$, is identified as the peak in the derivative $d\rho/dT$. Linear fits are performed above and below the midpoint transition and the intercepts are defined as $T_{\text{off}}$ and $T_{\text{on}}$, as labelled in the figure. $T_c$ from susceptibility is defined as the point at which diamagnetism occurs and deviates from the high-temperature background and it is closest to the offset temperature in transport. The critical temperatures used to build the phase diagrams in magnetic field were extracted using $T_{\text{off}}$ from the transport data. (b) The estimation of the upper critical field, $H_{\text{off}}$, from resistivity in pulsed magnetic field data measured at constant temperature using the same method as in (a). (c) Resistivity against temperature for different samples of CaKFe$_4$As$_4$ between 300 K and 2 K. The superconducting transition is very sharp, with $T_{c,0} = 35.0$ K and width $\Delta T_c = 0.15$ K, values typical for all measured single crystals indicating their high quality. (d) Resistivity data as a function of magnetic field for the sample S1 when $H||$($ab$) at 18 K. The dashed black line shows the linear extrapolation used to obtain the zero-field resistivity at 18 K and the intercept, $\rho_{H\rightarrow0}(T)$, and gradient are shown. Using this method, the extracted values of zero-field resistivity measured at constant temperatures are shown in the main paper in Fig. 1(f).
A. Experimental details.
Several high quality single crystals were used in this study with large residual resistivity ratios $RRR = \rho(300K)/\rho(36K) \sim 14.5$, small $\rho_0$ values of $\sim 9.2 \mu\Omega cm$ and sharp superconducting transitions with $\Delta T_c \sim 0.1 \text{K}$, as shown in Figs. 5(c) and Fig.1(f). Temperature sweeps were performed at constant magnetic field for different orientations, $H||c$ and $H||(ab)$ to build the high-temperature part of the $H_{c2}(T)$ phase diagram. Magnetic fields up to 90 T were produced by using current pulses through two different solenoid coils. An example of the magnetic field produced as a function of time is shown in Fig. 6.

![FIG. 6. Generation of the high-magnetic field pulse. Applied magnetic field as a function of time from the 90T magnet in Toulouse. The peak of this pulse was $\sim 88 \text{T}$ and is generated by overlaying pulsed current though two different coils. The pulse on the inner coil which generates the extremely high fields lasts $\sim 30 \text{ms}$.](image)

B. Determining superconducting coherence lengths.
The superconducting coherence lengths can be found in both field orientations near $T_c$ using the Ginzburg-Landau (GL) approach from the equations:

\[ \xi_{ab}^{GL} = \sqrt{\frac{\Phi_0}{2\pi\mu_0 \left| \frac{dH_{c2}^{ab}}{dT} \right| T_c}}, \quad \xi_c^{GL} = \sqrt{\frac{\Phi_0}{2\pi\mu_0 \left| \frac{dH_{c2}^{c}}{dT} \right| T_c \xi_{ab}^{GL}}} \]

where $\Phi_0$ is the magnetic flux quanta, $\mu_0 \left| \frac{dH_{c2}^{ab}}{dT} \right| T_c$ is the slope near $T_c$ when $H||c$, $\mu_0 \left| \frac{dH_{c2}^{c}}{dT} \right| T_c$ is the slope near $T_c$ when $H||(ab)$ and $\xi_{ab}^{GL}$ and $\xi_c^{GL}$ are the respective GL coherence lengths.

At the lowest temperature, the coherence lengths are extracted using $\mu_0 H_{c2}(T \to 0)$ and the following equations:

\[ \xi_{ab} = \sqrt{\frac{\Phi_0}{2\pi\mu_0 H_{c2}^{ab}(T \to 0)}}, \quad \xi_c = \sqrt{\frac{\Phi_0}{2\pi\mu_0 H_{c2}^{c}(T \to 0) \xi_{ab}}} \]

where $\xi_{ab}$ and $\xi_c$ are the coherence lengths in the $(ab)$-plane and along the $c$-axis, and $\mu_0 H_{c2}^{ab}(T \to 0)$ and $\mu_0 H_{c2}^{c}(T \to 0)$ are the critical fields at the lowest temperature when $H||c$ and $H||(ab)$ respectively. Using equations 2 at different constant temperatures, one can estimate $\xi_1 \to \xi(T)$ and $H_{c2} \to H_{c2}(T)$, and the anisotropy ratio, $\Gamma$, as shown in Fig.2(b) in the main text.

C. Depairing current density
Using the coherence length, one can also determine the critical depairing current density of a superconductor, $J_d$. As a function of temperature and magnetic field, this is be expressed as [24]:

\[ J_d(T, H) = \frac{2}{3\pi\lambda^2(T)} \sqrt{\frac{\mu_0(H_{c2}^2(T) - H^2)^{1/2}\Phi_0}{6\pi}}, \]

where $\lambda$ is the superconducting penetration depth and $\Phi_0$ is the magnetic flux quantum. At zero temperature and in no magnetic field, this gives

\[ J_d(0, 0) = \frac{2}{3\pi\lambda^2(0)} \sqrt{\frac{\mu_0 H_{c2}(0)\Phi_0}{6\pi}}. \]

Substituting $\mu_0 H_{c2} = \Phi_0/2\pi\xi^2$ this equation can be rearranged to give

\[ J_d(0, 0) = \frac{\Phi_0}{3\sqrt{3}\pi\lambda^2(0)\xi(0)} \]

Previous magnetisation reported $\mu_0 H_{c1} = 22(1) \text{mT}$ [14] when $H||c$ at low temperature which, combined with $H_{c2}$ values reported here, give $\kappa \sim 99(2)$ and $\lambda = 183(6)$ nm. Using

![FIG. 7. Coherence length extraction. Upper critical fields in CaKFe$_4$As$_4$ as a function of temperature. The dashed blue and red lines are linear fits near $T_c$ when $H||c$ and $H||(ab)$ respectively. The gradients of these fits (shown in the figure) were used to calculate the coherence lengths using the Ginzburg-Landau theory (equation 1). The solid blue and red lines are linear fits to the low temperature region when $H||c$ and $H||(ab)$ respectively. The zero-temperature extrapolation of $H_{c2}(T \to 0)$ for the two orientations were used to find the zero-temperature coherence lengths, as shown in the figure.](image)
$\xi = 1.86 \text{ nm}$, we find that the depairing current density is $J_\text{d} \sim 1.62 \times 10^8 \text{ A/cm}^2$, which is among the largest of any known iron-based superconductor.

**D. The upper critical fields using a two-band model.**

To describe the entire temperature dependence of $H_{c2}(T)$ for CaKFe$_4$As$_4$, including the upturn below ~10 K for both orientations, we use a two-band model in the clean limit. This model includes paramagnetic effects and allows the emergence of a FFLO state, as detailed in Ref. 1. The values of the upper critical field for different temperatures are found from estimating the following expressions:

\[
a_1[\ln t + U_1] + a_2[\ln t + U_2] + [\ln t + U_1][\ln t + U_2] = 0, \quad (6)
\]

where $a_1 = (\lambda_0 + \lambda_-)/2w$, $a_2 = (\lambda_0 - \lambda_-)/2w$, $\lambda_\pm = \lambda_{11} \pm \lambda_{22}$, $w = \lambda_{11}\lambda_{22} - \lambda_{12}\lambda_{21}$ and $\lambda_0 = (\lambda_+^2 + 4\lambda_{12}\lambda_{21})^{1/2}$. Here $\lambda_{ij}$ represents a coupling constant between bands $i$ and $j$, and as the cross-terms $\lambda_{12}$ and $\lambda_{21}$ only appear together we set $\lambda_{21} = \lambda_{12}$ for simplicity. The values of the coupling constants allow us to establish the dominant pairing. For $s^{+\pm}$ pairing the parameter $w > 0$ ($w \sim 0.248$ for the case presented in Fig. 3(c) and Fig. 9(c)) whereas for $s^\pm$ pairing $w < 0$ (Fig. 3(a) and (b), and Figs. 9(a) and 9(b)).

$U_1$ and $U_2$ are defined as

\[
U_1 = 2\varepsilon^2 \Re \sum_{n=0}^{\infty} \int_q \frac{du}{n+1/2} \tan^{-1} \left[ \frac{u\sqrt{b}}{t(n+1/2) + i\alpha b} \right] \quad (7)
\]

\[
U_2 = 2\varepsilon^2 s \Re \sum_{n=0}^{\infty} \int_q \frac{du}{\sqrt{q}} \tan^{-1} \left[ \frac{u\sqrt{\eta}}{t(n+1/2) + i\alpha b} \right] \quad (8)
\]

The variables used for this two-band model, $b$, $\alpha$, $q$, $\eta$, and $s$, are defined as

\[
b = \frac{\hbar^2 v_i^2 H_{c2}}{8\pi \phi_0 k_B T_c}, \quad \alpha = \frac{4\mu \phi_0 k_B T_c}{\hbar^2 v_i^2},
\]

\[
q^2 = \frac{Q_0^2 \phi_0 \epsilon_1}{2\pi H_{c2}}, \quad \eta = \frac{v_2}{v_1}, \quad s = \frac{\epsilon_2}{\epsilon_1}. \quad (9)
\]

$v_i$ is the in-plane Fermi velocity of band $i$, $\epsilon_i$ is the mass anisotropy ratio, $\epsilon_i = m_+^{1/2}/m_-^{1/2}$ is related to the ratio between the gradients near $T_c$ in different field orientations, $s$ is band mass anisotropy between the two bands and $\gamma = \epsilon^{-1/2}$. Various simulations of upper critical fields using this two-band model are shown in Fig. 8. The slope of $H_{c2}$ near $T_c$ of CaKFe$_4$As$_4$ is $-3.3$ for $H || c$ and $-10.8$ for $H || (ab)$, giving an $\epsilon \sim 1/10$. $Q$ is the magnitude of the FFLO modulation and it is found for a given temperature when $H_{c2}$ is maximal ($dH_{c2}/dQ = 0$). The simulations of $H_{c2}$ for $H || (ab)$ assumed that the bands have the same anisotropy parameter $\epsilon_1 = \epsilon_2 = \epsilon$. Other parameters are estimated based on the fitted values using a single-band model and the velocities are minimised locally to find an optimum solution. This approach was used for the two different $s^\pm$ and $s^{+\pm}$ pairing, which are described in the main body.

A rescaling of the upper critical field has been performed previously mapping $H_{c2}^{ab} \rightarrow H_{c2}^{ab}$ using $q_{ab} \rightarrow q_{c}e^{-3/4}$, $\alpha_{ab} \rightarrow \alpha_{c}e^{-1/2}$, $\eta_{ab} \rightarrow b_{c}/2e^{1/4}$ in $U_1$, $(\eta_{ab}b_{ab})^{1/2} \rightarrow (\eta_{c}b_{c}^{1/2})^{e^{1/4}}$ in $U_2$. The values of the $\alpha$ parameters change as $\alpha_{ab,1} \rightarrow \alpha_{c}e^{-1/2}$, and $\alpha_{ab,2} \rightarrow \alpha_{c}/(\eta_{c}e^{1/2})$. However, this rescaling has not been used in this study, as the ratio between the Fermi velocities $\eta$ is a variable parameter that can be changed between the two field orientations.

Previous studies on CaKFe$_4$As$_4$ have described the onset upper critical field data up to 60 T using the parameters $\lambda_{11} = \lambda_{22} = 0$, $\lambda_{12}\lambda_{21} = 0.25$, $\eta = 0.2$, $\alpha = 0.5$ and $\epsilon = 1/6$ and the above re-scaling [7]. Using these parameters we find that the onset upper critical field data (open blue and red symbols) clearly fail to describe the full temperature dependence of the upper critical field of CaKFe$_4$As$_4$, as shown in Fig. 9(a) and (b) (blue and red curves). As discussed in the main body of text, we can reasonably describe the upper critical field of CaKFe$_4$As$_4$ using a two-band model with band parameters for the $s^\pm$ and $s^{+\pm}$ pairing (see Table I), as shown in Fig. 9(c) and (e), respectively. We note here that an FFLO state can be stabilized at low temperatures for $H || (ab)$ (Fig. 9(c) and (e), right axis).

To further test the obtained parameters, we have modelled both the offset and onset critical fields for both field orientations assuming the $s^\pm$ and $s^{+\pm}$ pairing. The parameters for the two cases are listed in Table I and the simulations of the upper critical field are shown in Fig. 9. We find that the parameters describing the offset and onset upper critical fields are similar, with small differences found for the $\alpha$ values, which are slightly larger as the curvature for $H_{on}$ is greater as compared with the $H_{off}$ case. The velocities for $H_{on}$ are also slightly smaller due to the larger slopes near $T_c$, which scales as $|dH_{c2}/dT| T_c \propto 1/v^2$. Using the values for $H_{off}$ and $H_{on}$, we expected a ~20% difference in velocities when $H || c$, and a ~10% difference when $H || (ab)$, as shown in Table I. However, independent of the definition of the upper critical field, the stabilization of an FFLO state in CaKFe$_4$As$_4$ for $H || (ab)$ is realized in both cases.
FIG. 8. Two-band upper critical field simulations for different band coupling parameters and values of $\eta$. Simulations of the reduced upper critical field $h$ using the two-band model based on equations 6-9. The parameters listed in each panel correspond to $s^\pm$ pairing in (a) and (b) with $\lambda_{11} = \lambda_{22} = 0$, $\lambda_{12} = \lambda_{21} = 0.5$, $s^\pm$ pairing in (c) and (d) with $\lambda_{11} = \lambda_{22} = 0.81$, $\lambda_{12} = \lambda_{21} = 0.5$, and $s^{++}$ pairing in (e) and (f) with $\lambda_{11} = 0.81$, $\lambda_{22} = 0.29$ and $\lambda_{12} = \lambda_{21} = 0.1$, $\alpha_1 = 0.95$ for $H||c$. For panels (b), (d) and (f) the lower curves (left corners) represent the magnitude of the FFLO modulation, $Q/(2Q(0))$.

TABLE I. The different parameters used for the simulations of the upper critical field (defined either using an offset or onset magnetic field) using a two-band model and considering different pairing symmetries and magnetic field orientations in CaKFe$_4$As$_4$.

<table>
<thead>
<tr>
<th>$\mu_0 H_{\text{off}}$</th>
<th>$\mu_0 H_{\text{on}}$</th>
<th>$s^\pm$</th>
<th>$s^{++}$</th>
<th>$s^\pm$</th>
<th>$s^{++}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$H</td>
<td></td>
<td>c$</td>
<td>$H</td>
<td></td>
<td>ab$</td>
</tr>
<tr>
<td>$\lambda_{11}$</td>
<td>0</td>
<td>0.81</td>
<td>0</td>
<td>0</td>
<td>0.81</td>
</tr>
<tr>
<td>$\lambda_{22}$</td>
<td>0</td>
<td>0.5</td>
<td>0.29</td>
<td>0</td>
<td>0.29</td>
</tr>
<tr>
<td>$\lambda_{12}$</td>
<td>0.5</td>
<td>0.1</td>
<td>0.1</td>
<td>0.5</td>
<td>0.5</td>
</tr>
<tr>
<td>$\alpha_1$</td>
<td>0.95</td>
<td>3.1</td>
<td>0.5</td>
<td>3.2</td>
<td>1.5</td>
</tr>
<tr>
<td>$\alpha_2$</td>
<td>0.7</td>
<td>0</td>
<td>0</td>
<td>0</td>
<td>0</td>
</tr>
<tr>
<td>$\nu_1$ (meVÅ)</td>
<td>510(20)</td>
<td>253(20)</td>
<td>380(20)</td>
<td>195(20)</td>
<td>400(20)</td>
</tr>
<tr>
<td>$\nu_2$ (meVÅ)</td>
<td>40(4)</td>
<td>51(5)</td>
<td>54(4)</td>
<td>41(4)</td>
<td>36(3)</td>
</tr>
<tr>
<td>$\eta$</td>
<td>$\sim 0.006$</td>
<td>$\sim 0.04$</td>
<td>$\sim 0.02$</td>
<td>$\sim 0.04$</td>
<td>$\sim 0.008$</td>
</tr>
</tbody>
</table>
FIG. 9. Two-band upper critical field models for CaKFe₄As₄ using different band coupling parameters. (a) and (b) \( \lambda_{11} = \lambda_{22} = 0 \), \( \lambda_{12} = 0.25 \), \( \eta = 0.2 \), \( \alpha = 0.5 \) and \( \epsilon = 1/6 \) used previously to describe the onset upper critical field of CaKFe₄As₄ up to 60 T [7] when \( H \parallel |c| \) and \( H \parallel (ab) \) respectively. (c) \( s^\pm \) pairing with \( \lambda_{11} = \lambda_{22} = 0 \), \( \lambda_{12} = 0.25 \), \( \alpha = 0.5 \) and \( \epsilon = 1/6 \) used previously to describe the onset upper critical field of CaKFe₄As₄ up to 60 T [7] when \( H \parallel |c| \) and \( H \parallel (ab) \) respectively. (c) \( s^\pm \) pairing with \( \lambda_{11} = \lambda_{22} = 0 \), \( \lambda_{12} = 0.25 \), \( \alpha = 0.5 \) and \( \epsilon = 1/6 \) used previously to describe the onset upper critical field of CaKFe₄As₄ up to 60 T [7] when \( H \parallel |c| \) and \( H \parallel (ab) \) respectively. Here \( \alpha_1 = 0.95, \alpha_2 = 0 \) and \( \eta = 0.04 \) for \( H \parallel |c| \), and \( \alpha_1 = 3.1, \alpha_2 = 0.7 \) and \( \eta = 0.04 \) for \( H \parallel (ab) \). (d) \( s^\pm \) pairing for the onset critical field using the same parameters as in (c), but with \( \eta = 0.008 \) and \( \alpha_1 = 1.5 \) when \( H \parallel |c| \), and \( \alpha_1 = 4.2 \) when \( H \parallel (ab) \). (e) \( s^{++} \) pairing with \( \lambda_{11} = 0.81, \lambda_{22} = 0.29 \) and \( \lambda_{12} = 0.2 \). Here \( \alpha_1 = 0.95, \alpha_2 = 0 \) and \( \eta = 0.04 \) for \( H \parallel |c| \), and \( \alpha_1 = 3.1, \alpha_2 = 0.7 \) and \( \eta = 0.04 \) for \( H \parallel (ab) \). (f) \( s^{++} \) pairing for the onset critical field using the same parameters as in (e), but with \( \alpha_1 = 1.0 \) when \( H \parallel |c| \), and \( \alpha_1 = 3.5 \) when \( H \parallel (ab) \). In (c)-(f) blue lines show the two-band model (with no FFLO state present) when \( H \parallel |c| \), dashed black lines show the two-band model with no FFLO state when \( H \parallel (ab) \), and the red lines show the two-band model with an FFLO state when \( H \parallel (ab) \). The temperature dependence of the FFLO Q vector is shown by the dashed red lines (the right-axis in (c)-(f) for \( H \parallel (ab) \), and it is scaled to the zero-temperature value \( Q(0) \). We note that the FFLO state emerges when \( H \parallel (ab) \) regardless of the pairing limit or which critical field criteria is chosen. This reinforces the robustness of this result.